2SC2612

Silicon NPN Triple Diffused

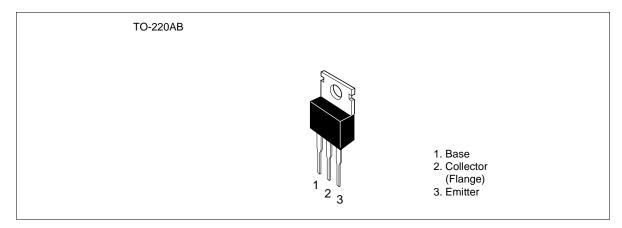
HITACHI

ADE-208-885 (Z) 1st. Edition Sep. 2000

Application

High voltage, high speed and high power switching

Outline



Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	500	V
Collector to emitter voltage	V _{CEO}	400	V
Emitter to base voltage	V _{EBO}	7	V
Collector current	I _c	3	A
Collector peak current	I _{C(peak)}	6	А
Base current	I _B	1.5	A
Collector power dissipation	P _C *1	30	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. Value at $T_c = 25^{\circ}C$.

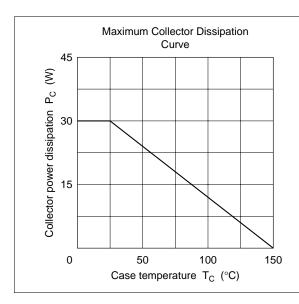


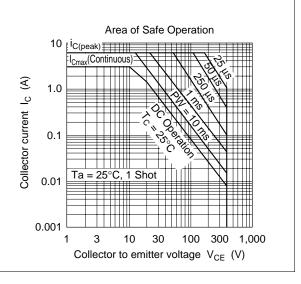
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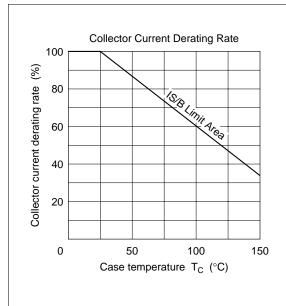
Electrical Characteristics ($Ta = 25^{\circ}C$)

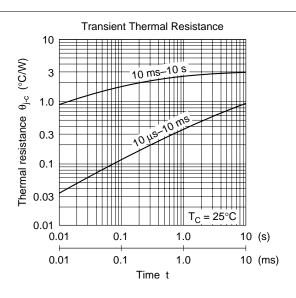
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter sustain voltage	$V_{\text{CEO(sus)}}$	400	_	_	V	$I_{\rm C} = 0.2 \; {\rm A}, \; {\rm R}_{\rm BE} = \infty, \ {\rm L} = 100 \; {\rm mH}$
	V _{CEX(sus)}	400	_	_	V	$I_{C} = 3 \text{ A}, I_{B1} = -I_{B2} = 0.6 \text{ A}$ $V_{BE} = -5 \text{ V}, L = 180 \mu\text{H},$ Clamped
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	_	_	V	$I_{E} = 10 \text{ mA}, I_{C} = 0$
Collector cutoff current	I _{CBO}	_	_	100	μΑ	$V_{CB} = 400 \text{ V}, I_{E} = 0$
	I _{CEO}	_	_	100	μΑ	$V_{CE} = 350 \text{ V}, R_{BE} = \infty$
DC current transfer ratio	h _{FE1}	15	_	_		$V_{CE} = 5 \text{ V}, I_{C} = 1.5 \text{ A}^{*1}$
	h_{FE2}	7	_	_		$V_{CE} = 5 \text{ V}, I_{C} = 3.0 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	1.0	V	$I_{\rm C} = 1.5 \text{ A}, I_{\rm B} = 0.3 \text{ A}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)}$	_	_	1.5	V	$I_{\rm C} = 1.5 \text{ A}, I_{\rm B} = 0.3 \text{ A}^{*1}$
Turn on time	t _{on}	_	_	1.0	μs	$I_C = 3 \text{ A}, I_{B1} = -I_{B2} = 0.6 \text{ A},$
Storage time	t _{stg}		1.2	2.5	μs	V _{CC} ≅ 150 V
Fall time	t _f	_	_	1.0	μs	

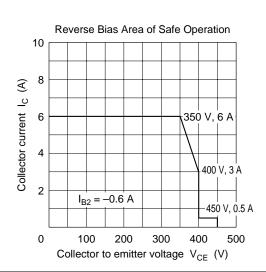
Note: 1. Pulse test

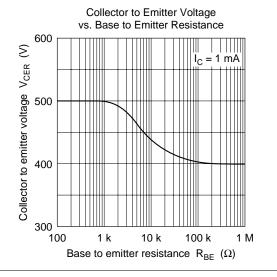


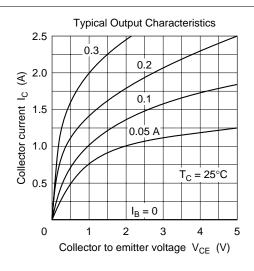


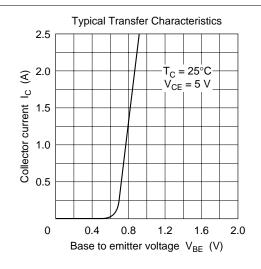


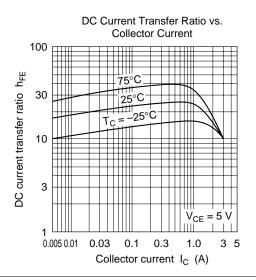


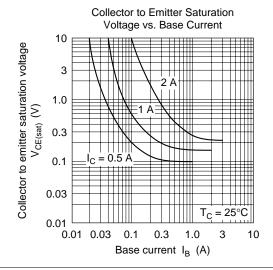


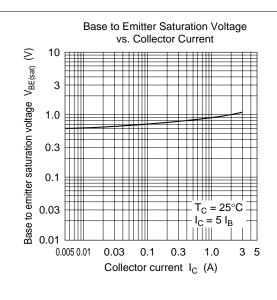


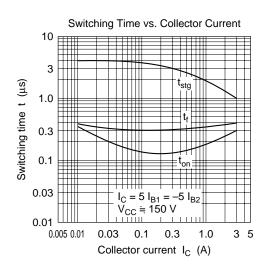


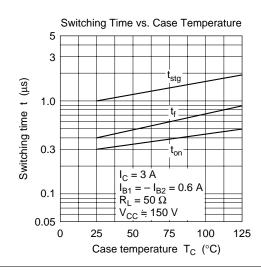




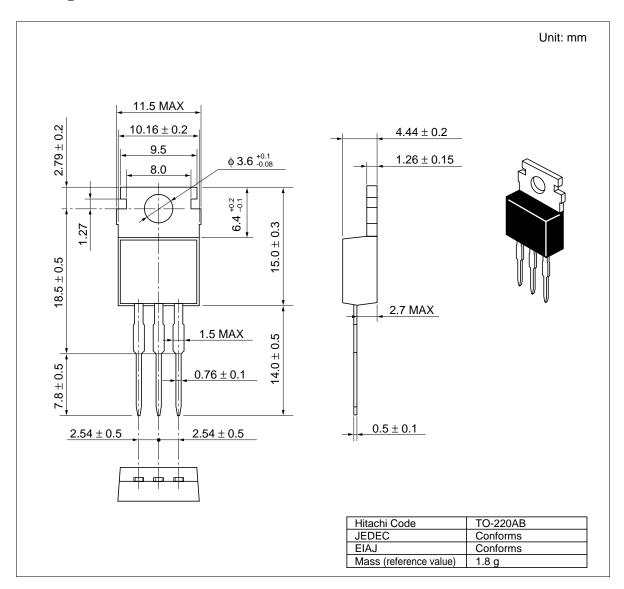








Package Dimensions



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Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica Europe Asia

Japan

http://semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg http://sicapac.hitachi-asia.com http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Germany Fax: <1>(408) 433-0223

Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585160

Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00, Singapore 049318 Tel: <65>-538-6533/538-8577 Fax: <65>-538-6933/538-3877 URL: http://www.hitachi.com.sg

Hitachi Asia I td (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road,

Hung-Kuo Building. Taipei (105), Taiwan Tel: <886>-(2)-2718-3666 Fax: <886>-(2)-2718-8180

Telex: 23222 HAS-TP URL: http://www.hitachi.com.tw Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon,

Hong Kong

Tel: <852>-(2)-735-9218 Fax: <852>-(2)-730-0281 URL: http://www.hitachi.com.hk

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